IMH20TR1G

Dual Bias Resistor Transistor

NPN Surface Mount

- Low V_{CC} (sat) 80 mV max at IC/IB = 50 mA/2.5 mA
- High Current: I_C = 600 mA max WWW.DZSC.COM
- This is a Pb-Free Device

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	30	Vdc
Collector–Emitter Voltage	V _{(BR)CEO}	15	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	5.0	Vdc
Collector Current – Continuous	I _C	600	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation*	P _D	300	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

^{*}Total for both Transistors.

Q1 + Q2: NPN

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

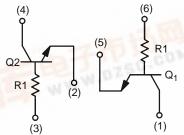
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Characteristic	Symbol	Min	Max	Unit	
Collector–Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0)	V _(BR) CEO	15	-	Vdc	
Collector-Base Breakdown Voltage ($I_C = 50 \mu Adc, I_E = 0$)	V _{(BR)CBO}	30	-	Vdc	
Emitter–Base Breakdown Voltage ($I_E = 50 \mu Adc, I_C = 0$)	V _{(BR)EBO}	5.0	-	Vdc	
Collector–Base Cutoff Current $(V_{CB} = 20 \text{ Vdc}, I_E = 0)$	I _{CBO}	-	0.5	μAdc	
Emitter–Base Cutoff Current $(V_{EB} = 4.0 \text{ V}, I_{C} = 0)$	I _{EBO}	150	0.5	μAdc	
DC Current Gain (Note 1) (V _{CE} = 5.0 Vdc, I _C = 50 mAdc)	h _{FE}	100	600	-	
Collector–Emitter Saturation Voltage (I _C = 50 mAdc, I _B = 2.5 mAdc)	V _{CE(sat)}	-	80	mV	
Input Resistance	R ₁	1.54	2.86	kΩ	

^{1.} Pulse Test: Pulse Width \leq 300 μ s, D.C. \leq 2%.



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SC-74



SC-74R 318AA Style 21





H20 = Specific Device Code M = Date Code

ORDERING INFORMATION

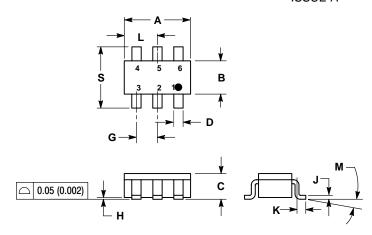
Device	Package	Shipping [†]	
IMH20TR1G	SC-74R	3000/Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

IMH20TR1G

PACKAGE DIMENSIONS

SC-74R CASE 318AA-01 ISSUE A



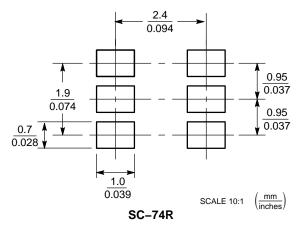
NOTES

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1142	0.1220	2.90	3.10
В	0.0512	0.0669	1.30	1.70
С	0.0354	0.0433	0.90	1.10
D	0.0098	0.0197	0.25	0.50
G	0.0335	0.0413	0.85	1.05
Н	0.0005	0.0040	0.013	0.100
J	0.0040	0.0102	0.10	0.26
K	0.0079	0.0236	0.20	0.60
L	0.0493	0.0649	1.25	1.65
М	0°	10°	0 °	10°
S	0.0985	0.1181	2.50	3.00

- STYLE 21:
 PIN 1. COLLECTOR 1
 2. EMITTER 2
 3. BASE 2
 4. COLLECTOR 2
 5. EMITTER 1

 - 6. BASE 1
- **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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